MBRF20200CT

Preferred Device

SWITCHMODE[™] Schottky Power Rectifier

The SWITCHMODE Power Rectifier employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-artgeometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for use as rectifiers in very low-voltage, high-frequency switching power supplies, free wheeling diodes and polarity protection diodes.

Features

- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
- Matched Dual Die Construction
- High Junction Temperature Capability
- High dv/dt Capability
- Guardring for Stress Protection
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Electrically Isolated. No Isolation Hardware Required.
- Pb-Free Package is Available*

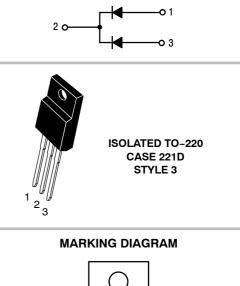
Mechanical Characteristics:

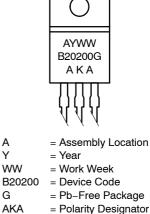
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 20 AMPERES, 200 VOLTS





Device	Package	Shipping
MBRF20200CT	TO-220	50 Units/Rail
MBRF20200CTG	TO-220 (Pb-Free)	50 Units/Rail

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Preferred devices are recommended choices for future use and best overall value.

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MAXIMUM RATINGS (Per Leg)

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	200	V
Average Rectified Forward Current (Rated V_R) T_C = 125°C	Per Leg Per Package	I _{F(AV)}	10 20	A
Peak Repetitive Forward Current, Per Leg	(Rated V _R , Square Wave, 20 kHz) T _C = 90° C	I _{FRM}	20	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions hal	fwave, single phase, 60 Hz)	I _{FSM}	150	A
Peak Repetitive Reverse Surge Current (2.0	μs, 1.0 kHz)	I _{RRM}	1.0	А
Operating Junction Temperature and Storage	e Temperature	T _J , T _{stg}	-65 to +150	°C
Voltage Rate of Change (Rated V_R)		dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

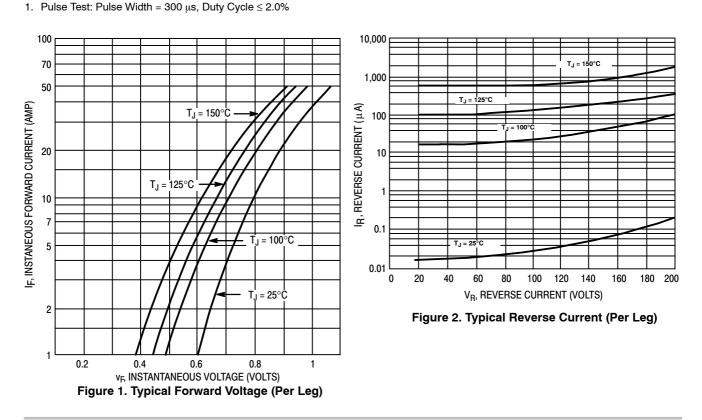
THERMAL CHARACTERISTICS (Per Leg)

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{ ext{ heta}JC}$	3.5	°C/W

ELECTRICAL CHARACTERISTICS (Per Leg)

Rating	Symbol	Мах	Unit
Maximum Instantaneous Forward Voltage (Note 1)	VF		V
(i _F = 10 Amp, T _C = 25°C)		0.9	
(i _F = 10 Amp, T _C = 125°C)		0.8	
(i _F = 20 Amp, T _C = 25°C)		1.0	
(i _F = 20 Amp, T _C = 125°C)		0.9	
Maximum Instantaneous Reverse Current (Note 1)	i _B		mA
(Rated dc Voltage, T _C = 25°C)		1.0	
(Rated dc Voltage, $T_C = 125^{\circ}C$)		50	
DYNAMIC CHARACTERISTICS (Per Leg)			
Capacitance ($V_R = -5.0 \text{ V}, T_C = 25^{\circ}\text{C}, \text{ Freq.} = 1.0 \text{ MHz}$)	CT	500	pF

Capacitance ($V_R = -5.0 \text{ V}, T_C = 25^{\circ}\text{C}, \text{ Freq.} = 1.0 \text{ MHz}$)



MBRF20200CT

TEST CONDITION FOR ISOLATION TEST*

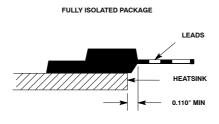
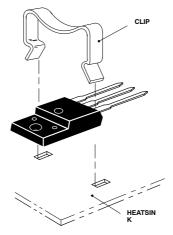


Figure 3. Mounting Position

*Measurement made between leads and heatsink with all leads shorted together.

MOUNTING INFORMATION

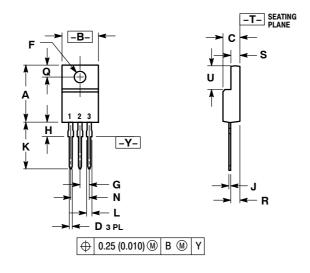


Clip-Mounted

Figure 4. Typical Mounting Technique

PACKAGE DIMENSIONS

TO-220 FULLPAK CASE 221D-03 ISSUE J



	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.617	0.635	15.67	16.12
В	0.392	0.419	9.96	10.63
С	0.177	0.193	4.50	4.90
D	0.024	0.039	0.60	1.00
F	0.116	0.129	2.95	3.28
G	0.100 BSC		2.54 BSC	
Н	0.118	0.135	3.00	3.43
J	0.018	0.025	0.45	0.63
K	0.503	0.541	12.78	13.73
L	0.048	0.058	1.23	1.47
Ν	0.200 BSC		5.08 BSC	
Q	0.122	0.138	3.10	3.50
R	0.099	0.117	2.51	2.96
S	0.092	0.113	2.34	2.87
U	0.239	0.271	6.06	6.88

1. DIMENSIONING AND TOLERANCING PER ANSI

CONTROLLING DIMENSION: INCH

STYLE 3: PIN 1. ANODE

NOTES:

2

3.

Y14.5M, 1982

CATHODE
ANODE

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